NSN 5961-01-375-0808



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-375-0808 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.033 inches and 0.047 inches Overall Width: Between 0.047 inches and 0.055 inches **End Application:** 6625-01-286-3566 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Cubic Measure:** 0.0003 cubic inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 0.35 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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